

Nanostructured surfaces

Influence of growth condition and thermal treatment of thin Cu₂O film obtained by magnetron sputtering on transmission spectra

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In present time there are intensive works to obtain technology, which allows to produce low-cost solar panels to mass using. Area of researches has been focused on about 10 chemical compounds, from which the most promising is copper oxide Cu₂O. Photovoltaic effect was observed for example for structures ZnO/Cu₂O, Ga₂O₃/Cu₂O and TiO₂/Cu₂O [1].

It is commonly known, that condition of growth as well as thermal treatment after growth can affect on physico-chemical properties of thin layers [2]. One of characteristic parameter of films is their transmission, which describe their optical quality.

In this work the results of researches of depending transmission spectrum of Cu₂O film on glass versus conditions of growth and heating in air will be presented. Analysis of results leads to conclusion that transmission highly dependent on mentioned factors. Furthermore, there was observed that transmission of layer changed in time, which will be also a matter of discuss.

[1] M. Pavan, S. Rühle, A. Ginsburg, D. A.Keller, Hannah-Noa Barad, P. M.Sberna, D. Nunes, Rodrigo Martins, Assaf Y.Anderson, Arie Zaban, Elvira Fortunato „TiO₂/Cu₂O all-oxideheterojunction solar cells produced by spray pyrolysis” // Solar Energy Materials & Solar Cells132(2015)549–556

[2] A.S. Usikov, W.V. Lundin, D.A. Bedarev, E.E. Zavarin, A.V. Sakharov, A.F.Tsatsul'nikov, Zh.I.Alferov, N.N. Ledentsov, A. Hoffmann, D. Bimberg. Influence of the thick GaN buffer growth conditions on the electroluminescence properties of GaN/InGaN multilayer heterostructures. // Proceedings of IWN2000, Nagoya, September 24-27, 2000, pp. 875-877